

ATTY. DOCKET NO.  
37392SERIAL NO.  
10/521,879INFORMATION DISCLOSURE CITATION  
BY APPLICANT  
(USE SEVERAL SHEETS IF NECESSARY)APPLICANT:  
Fabrice Pardo et al.FILING DATE:  
January 21, 2005GROUP ART UNIT:  
2814

## U.S. PATENT DOCUMENTS

Examiner Initial		Document No.	Date	Name	Class	Subclass	Filing Date if Appropriate
JCI	A	5,227,648	07/1993	Woo			
JCI	B	5,663,639	09/1997	Brown et al.			
	C						
	D						
	E						

## FOREIGN PATENT DOCUMENTS

		Document No.	Date	Country	Class	Subclass	Translation
JCI	F	0 651 448 A1	03/1995	European			Corresponds to U.S. Patent No.: 5,512,763
	G	2 803 950	07/2001	France			Corresponds to U.S. Publication No.: 2003/010979
	H						

## OTHER REFERENCES (Including Author, Title, Date, Pertinent Pages, Etc.)

JCI	I	Katsumi Kishino et al., "Resonant Cavity-Enhanced (RCE) Photodetectors, August 8, 2001, pages 2025 - 2034,
JCI	J	Wolfgang Kowalsky et al., "High Bandwidth Metal-Semiconductor-Metal Photodiodes with Integrated Fabry-Perot Resonator for WDM Receivers", August 1992, Pages 214 - 216
JCI	K	A. Strittmatter et al., "High-Speed, High Efficiency Resonant-Cavity Enhanced InGaAs MSM Photodetectors", Pages 1231- 1232
JCI	L	A. Strittmatter et al., "High-Frequency, Long-Wavelength Resonant-Cavity-Enhanced InGaAs MSM Photodetectors", September 15, 1996, Pages 145 - 148

Examiner: /John Ingham/ Date Considered 08/14/2006

\*Examiner: Initial if reference considered, regardless of whether citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.